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Substitute for form 1449A/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Sheet 1 of 1

Complete if Known

Application Number	
Filing Date	11/26/2003
First Named Inventor	TADAHIRO OHMI
Art Unit	2818
Examiner Name	David Vu
Attorney Docket Number	040258-0306939

U. S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
	1	US- 6,479,392	11-12-2002	YAMAZAKI et al.	
	2	US- 6,380,033	04-30-2002	HE et al.	
	3	US- 2001/0044187	11-22-2001	JOO et al.	
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FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				
	A	JP 5-267684	10-15-1993	OZAWA		
	B	JP 59-105371	06-18-1984	KOMORI		
	C	JP 8-51164	02-20-1996	MORITA		
	D	JP 9-205155	08-05-1997	TAKABAYASHI		
	E	JP 9-213820	08-15-1997	USHIYAMA et al.		

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Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>				Complete if Known	
				Application Number	
				Filing Date	11/26/2003
				First Named Inventor	TADAHIRO OHMI
				Art Unit	2818
Examiner Name					
Sheet	1	of	1	Attorney Docket Number	040258-0306939

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	A	ITO ET AL., "Silicon Oxynitridation With Inductively Coupled Oxygen-Nitrogen Mixed Plasma," Japan J. Appl. Phys., p. 612-616, (1997).	
	B	HIRAYAMA ET AL., "Low-Temperature Growth of High-Integrity Silicon Oxide Films by Oxygen Radical Generated in High-Density Krypton Plasma," IEDM, p. 249-252, (1999).	
	C	SAITO ET AL., "Low Temperature Formation of Gate-Grade Silicon Nitride Film Employing Microwave-Excitation High-Density Plasma," Technical Report of IEICE, p. 85-90, (1999).	

Examiner Signature		Date Considered	
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